

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1.5 kV HBM
- Drain-source on-state resistance R_{DSon} = 59 m Ω
- Very low gate-source threshold voltage for portable applications $V_{GS(th)}$ = -0.68 V

3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-12	V
V _{GS}	gate-source voltage	-		-8	-	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-3.2	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C		-	59	72	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G (The provide state of the p
4	D	drain	Transparent top view	S 017aaa259
			DFN1010D-3 (SOT1215)	

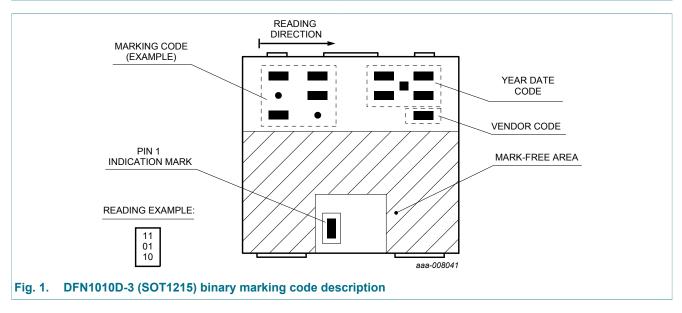
6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB65UPE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMXB65UPE	01 10 00



8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit		
V _{DS}	drain-source voltage	T _j = 25 °C		-	-12	V		
V _{GS}	gate-source voltage			-8	8	V		
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-3.2	А		
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-2.1	А		
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-13	А		
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	317	mW		
			[1]	-	1070	mW		
		T _{sp} = 25 °C		-	8330	mW		
Tj	junction temperature			-55	150	°C		
T _{amb}	ambient temperature			-55	150	°C		
T _{stg}	storage temperature			-65	150	°C		
Source-dra	Source-drain diode							
I _S	source current	T _{amb} = 25 °C	[1]	-	-1	А		

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

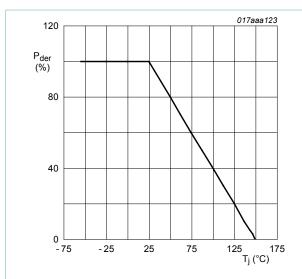


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

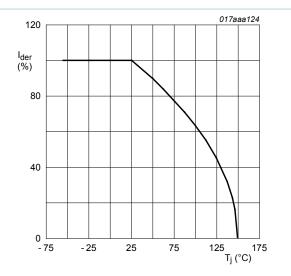
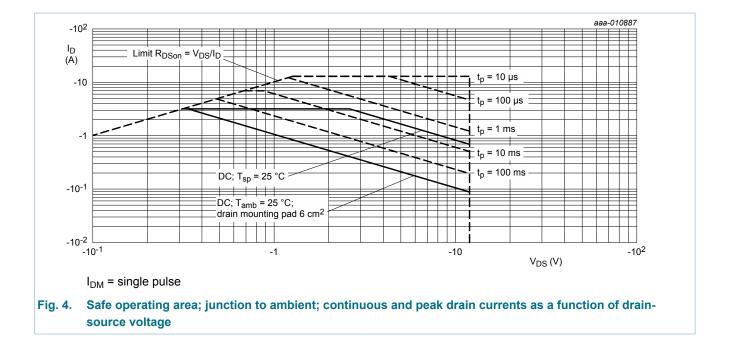


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

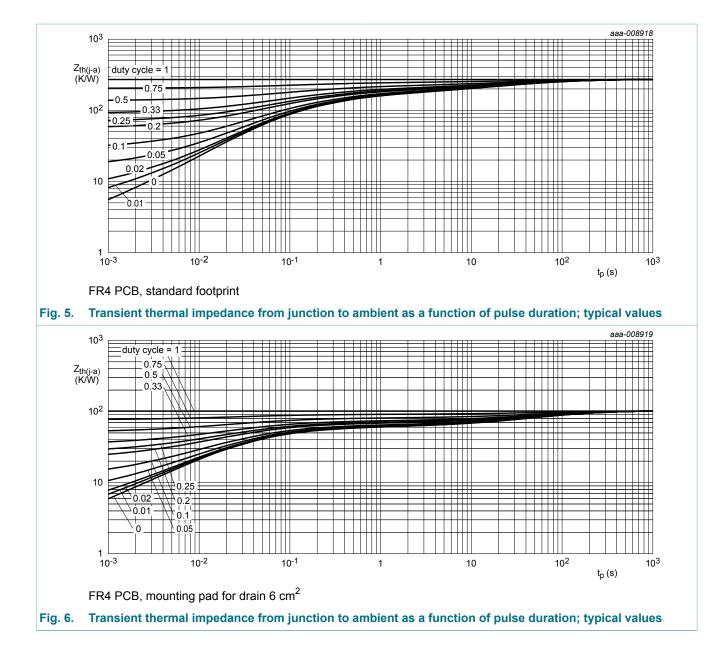
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance in free air from junction to ambient	in free air	[1]	-	271	312	K/W
			[2]	-	102	117	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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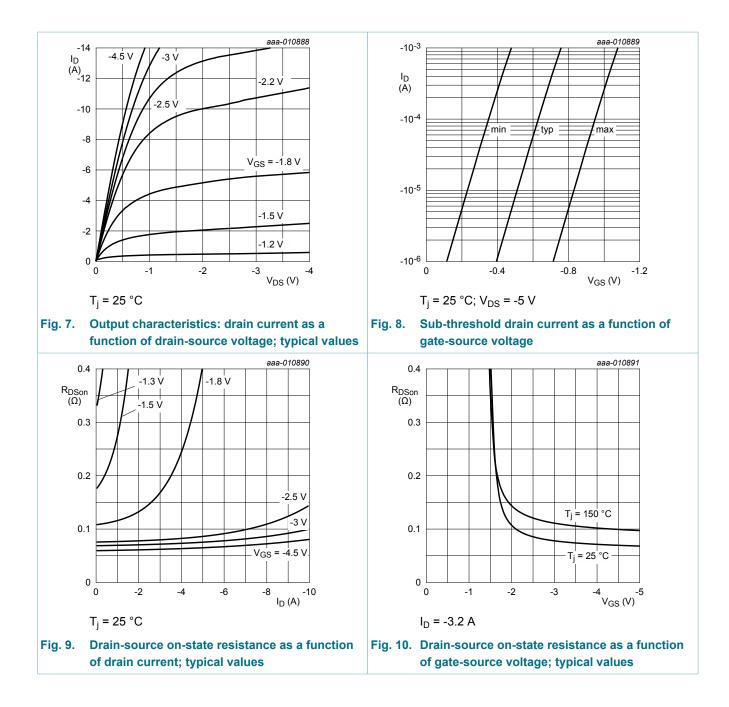
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-12	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.4	-0.68	-1	V
I _{DSS}	drain leakage current	V_{DS} = -12 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C	-	59	72	mΩ
	resistance	V_{GS} = -4.5 V; I _D = -3.2 A; T _j = 150 °C	-	80	98	mΩ
		V_{GS} = -2.5 V; I _D = -2.7 A; T _j = 25 °C	-	78	98	mΩ
		V_{GS} = -1.8 V; I _D = -0.4 A; T _j = 25 °C	-	120	200	mΩ
		V _{GS} = -1.5 V; I _D = -50 mA; T _j = 25 °C	-	198	450	mΩ
		V _{GS} = -1.2 V; I _D = -10 mA; T _j = 25 °C	-	880	-	mΩ
9 _{fs}	forward transconductance	V_{DS} = -10 V; I_D = -2 A; T_j = 25 °C	-	9.4	-	S
R _G	gate resistance	f = 1 MHz	-	8.7	-	Ω
Dynamic ch	aracteristics	· · · ·	I			
Q _{G(tot)}	total gate charge	V_{DS} = -6 V; I _D = -3.2 A; V _{GS} = -4.5 V;	-	6.7	12	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1	-	nC
Q _{GD}	gate-drain charge		-	1.9	-	nC
C _{iss}	input capacitance	V _{DS} = -6 V; f = 1 MHz; V _{GS} = 0 V;	-	634	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	167	-	pF
C _{rss}	reverse transfer capacitance		-	146	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -6 V; I _D = -3.2 A; V _{GS} = -4.5 V;	-	6.2	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	22	-	ns
t _{d(off)}	turn-off delay time	1	-	27	-	ns
t _f	fall time		-	17	-	ns
Source-drai	n diode	1				
V _{SD}	source-drain voltage	I _S = -1 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

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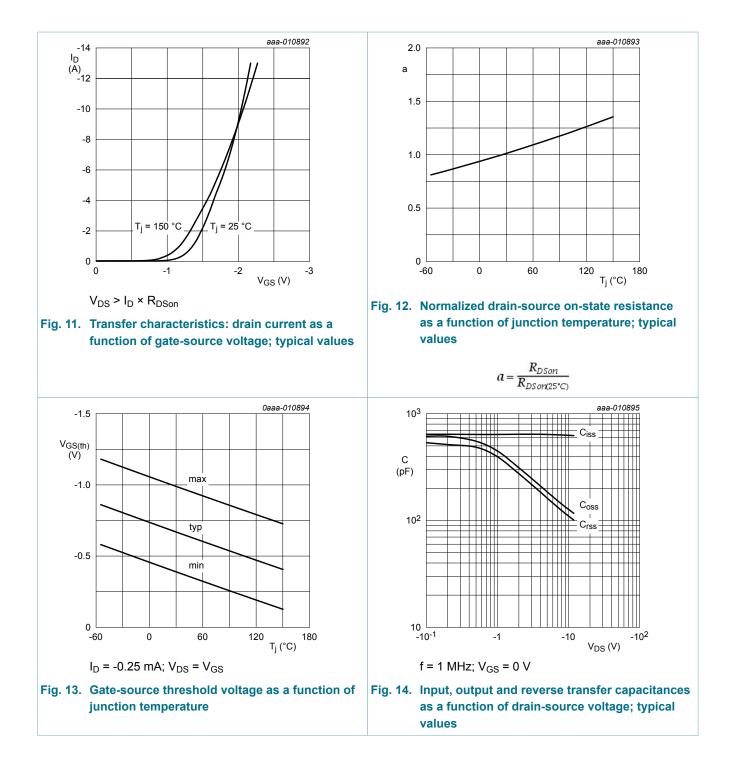
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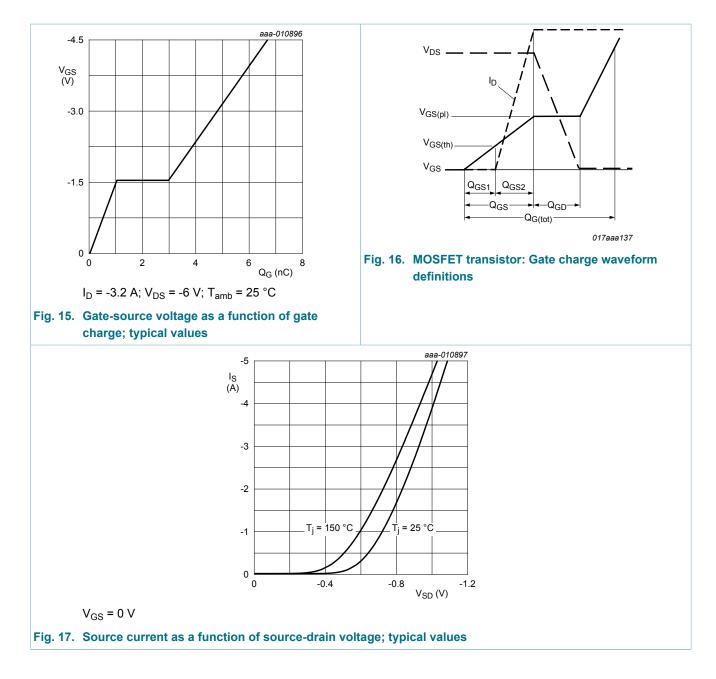
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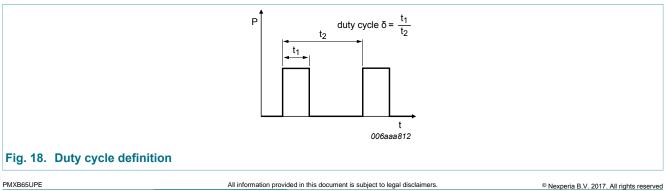
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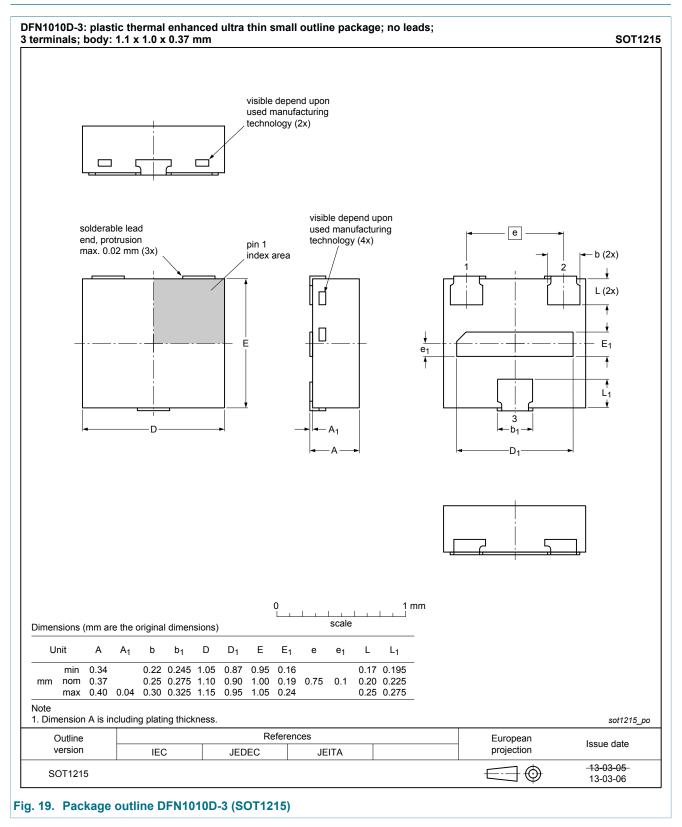


11. Test information



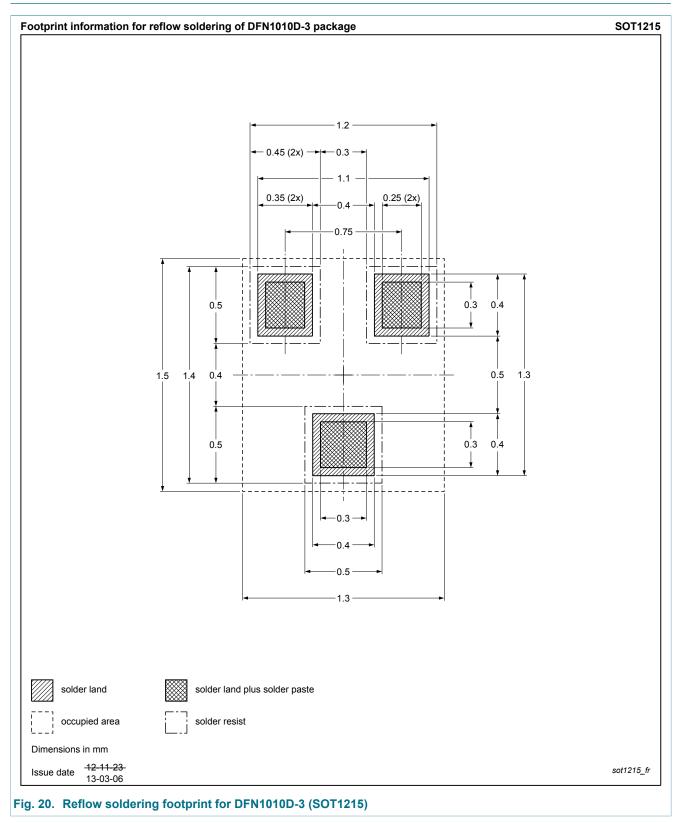
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12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB65UPE v.3	20140708	Product data sheet	-	PMXB65UPE v.2
Modifications:	Product status char	nged		
PMXB65UPE v.2	20140218	Preliminary data sheet	-	PMXB65UPE v.1
PMXB65UPE v.1	20140204	Preliminary data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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